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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR 2SJ605

SWITCHING P-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SJ605 is P-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

Super low on-state resistance:

RDS(on)1 = 20 m Ω MAX. (Vgs = -10 V, ID = -33 A)

 $R_{DS(on)2} = 31~m\Omega$ MAX. (Vgs = -4.0~V, ID = -33~A)

· Low input capacitance

★ $C_{iss} = 4600 \text{ pF TYP.} (V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ A})$

• Built-in gate protection diode

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SJ605	TO-220AB
2SJ605-S	TO-262
2SJ605-ZJ	TO-263
2SJ605-Z	TO-220SMD ^{Note}

Note TO-220SMD package is produced only in Japan.

(TO-220AB)

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (V _{GS} = 0 V)	VDSS	-60	V
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	∓ 20	V
Drain Current (DC) (Tc = 25°C)	I _{D(DC)}	∓ 65	Α
Drain Current (pulse) Note1	I _{D(pulse)}	∓ 200	Α
Total Power Dissipation (Tc = 25°C)	Рт	100	W
Total Power Dissipation (T _A = 25°C)	Рт	1.5	W
Channel Temperature	Tch	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C
Single Avalanche Current Note2	las	-45	Α
Single Avalanche Energy Note2	Eas	203	mJ

Notes 1. PW \leq 10 μ s, Duty cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = -30 V, R_G = 25 Ω , V_{GS} = -20 \rightarrow 0 V



(TO-262)



(TO-263, TO-220SMD)



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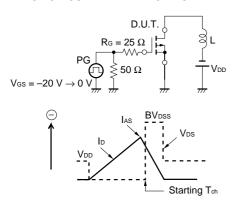


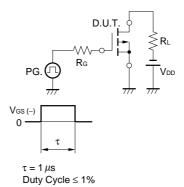
ELECTRICAL CHARACTERISTICS (TA = 25°C)

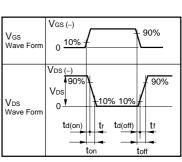
	CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Zero Gate Voltage Drain Current	IDSS	V _{DS} = -60 V, V _{GS} = 0 V			-10	μΑ
	Gate Leakage Current	Igss	$V_{GS} = \mp 20 \text{V}, V_{DS} = 0 \text{V}$			∓ 10	μΑ
*	Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = -10 V, I _D = -1 mA	-1.5	-2.0	-2.5	V
	Forward Transfer Admittance	yfs	V _{DS} = -10 V, I _D = -33 A	30	59		S
	Drain to Source On-state Resistance	R _{DS(on)1}	Vgs = -10 V, Ib = -33 A		17	20	mΩ
		R _{DS(on)2}	Vgs = -4.0 V, ID = -33 A		22	31	mΩ
	Input Capacitance	Ciss	V _{DS} = -10 V		4600		pF
	Output Capacitance	Coss	V _{GS} = 0 V		820		pF
*	Reverse Transfer Capacitance	Crss	f = 1 MHz		330		pF
	Turn-on Delay Time	td(on)	V _{DD} = -30 V, I _D = -33 A		15		ns
	Rise Time	tr	V _{GS} = -10 V		14		ns
	Turn-off Delay Time	td(off)	$R_G = 0 \Omega$		100		ns
	Fall Time	tf			58		ns
	Total Gate Charge	Q _G	V _{DD} = -48 V		87		nC
	Gate to Source Charge	Qgs	V _{GS} = -10 V		15		nC
	Gate to Drain Charge	Q _{GD}	Ib = -65 A		22		nC
*	Body Diode Forward Voltage	V _F (S-D)	IF = 65 A, Vgs = 0 V		1.0		V
*	Reverse Recovery Time	trr	I _F = 65 A, V _{GS} = 0 V		53		ns
*	Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		110		nC

TEST CIRCUIT 1 AVALANCHE CAPABILITY

* TEST CIRCUIT 2 SWITCHING TIME



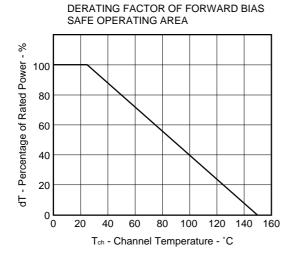


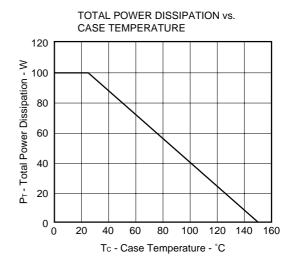


TEST CIRCUIT 3 GATE CHARGE

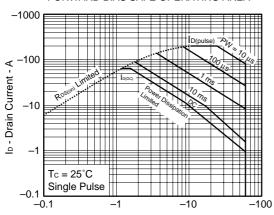


★ TYPICAL CHARACTERISTICS (TA = 25°C)



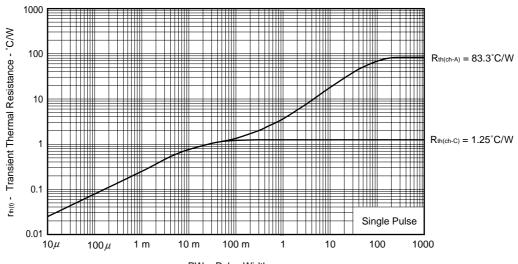


FORWARD BIAS SAFE OPERATING AREA



V_{DS} - Drain to Source Voltage - V

TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

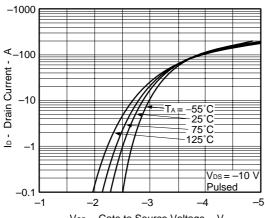


PW - Pulse Width - s

3

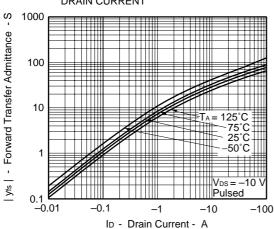


FORWARD TRANSFER CHARACTERISTICS

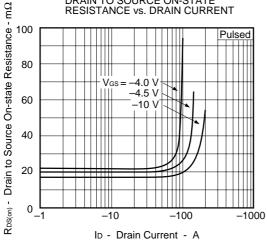


V_{GS} - Gate to Source Voltage - V

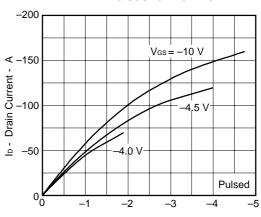
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

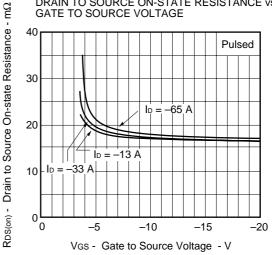


DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

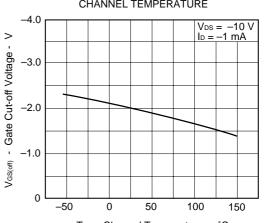


V_{DS} - Drain to Source Voltage - V

DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

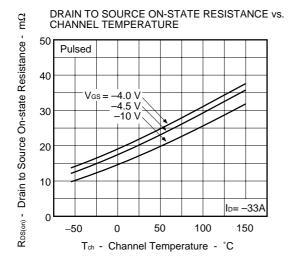


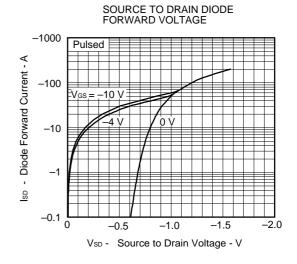
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

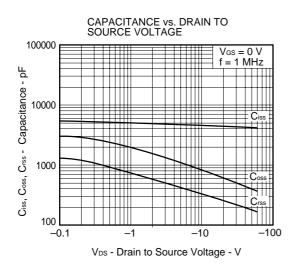


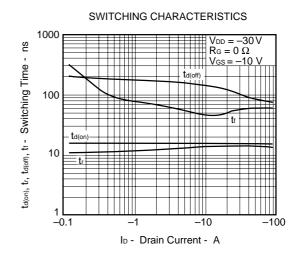
Tch - Channel Temperature - °C

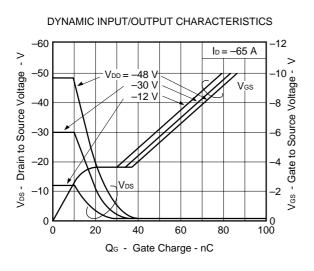


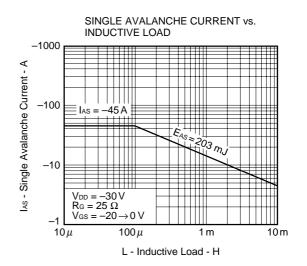




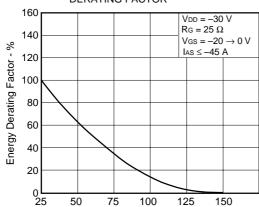








SINGLE AVALANCHE ENERGY DERATING FACTOR

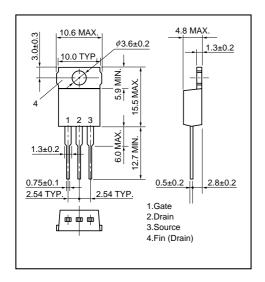


Starting Tch - Starting Channel Temperature - °C

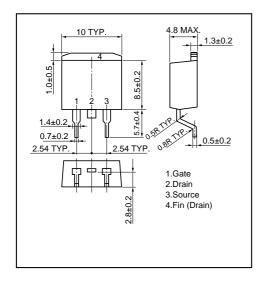


★ PACKAGE DRAWINGS(Unit: mm)

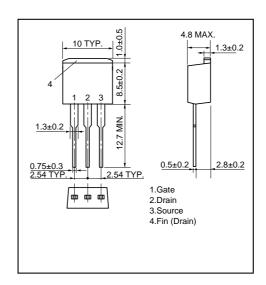
1) TO-220AB(MP-25)



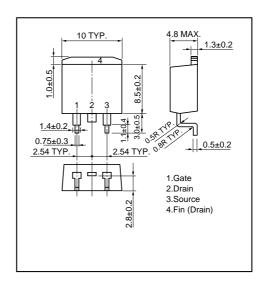
3) TO-263 (MP-25ZJ)



2) TO-262(MP-25 Fin Cut)

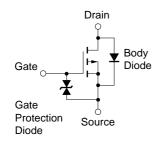


4) TO-220SMD(MP-25Z)^{Note}



Note This package is produced only in Japan.

EQUIVALENT CIRCUIT



Remark

The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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